NSN 5961-00-767-2120

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-767-2120 **Inclosure Material:** Metal **Overall Length:** 0.266 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case: Emitter Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.100 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 1.50 amperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No